

HAC RF TESTREPORT

No. I16Z42044-SEM02

For

TCL Communication Ltd.

HSUPA/HSDPA/UMTS Tri Band/GSM Quad Band/LTE Tri Band mobile phone

Model Name: 4044W, 4044N

With

Hardware Version: 03

Software Version: C4N

FCC ID: 2ACCJN011

Results Summary: M Category = M4

Issued Date: 2016-12-16



Note

The test results in this test report relate only to the devices specified in this report. This report shall not be reproduced except in full without the written approval of CTTL.

Test Laboratory:

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REPORT HISTORY

Report Number	Revision	Issue Date	Description
I16Z42044-SEM02	Rev.0	2016-12-16	Initial creation of test report



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1 Test Laboratory

1.1 Testing Location

Company Name:	CTTL(Shouxiang)
Address:	No. 51 Shouxiang Science Building, Xueyuan Road, Haidian District,
	Beijing, P. R. China100191

1.2 Testing Environment

Temperature:	18°C~25°C,			
Relative humidity:	30%~ 70%			
Ground system resistance:	< 0.5 Ω			

Ambient noise is checked and found very low and in compliance with requirement of standards.

Reflection of surrounding objects is minimized and in compliance with requirement of standards

1.3 Project Data

Project Leader:	Qi Dianyuan
Test Engineer:	Lin Hao
Testing Start Date:	November 3, 2016
Testing End Date:	November 3, 2016

1.4 Signature

Lin Xiaojun

(Prepared this test report)

Qi Dianyuan

(Reviewed this test report)

Lu Bingsong

Deputy Director of the laboratory

(Approved this test report)



2 Client Information

2.1 Applicant Information

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2.2 Manufacturer Information

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3 Equipment Under Test (EUT) and Ancillary Equipment (AE)

This EUT is a variant product and the report of original sample is No.l16Z42016-SEM02. According to the client request, we quote the test results of original sample directly.

3.1 About EUT

Description:	HSUPA/HSDPA/UMTS Tri Band/GSM Quad Band/LTE Tri Band mobile phone
Model name:	4044W, 4044N
Operating	GSM 850/900/1800/1900, WCDMA 850/1700/1900
mode(s):	BT, Wi-Fi, LTE Band 2/4/12

3.2 Internal Identification of EUT used during the test

EUT ID*	IMEI	HW Version	SW Version
EUT1	/	03	C4N

^{*}EUT ID: is used to identify the test sample in the lab internally.

3.3 Internal Identification of AE used during the test

AE ID*	Description	Model	SN	Manufacturer
AE1	Battery	TLi013C1	/	BYD

^{*}AE ID: is used to identify the test sample in the lab internally.

3.4 Air Interfaces / Bands Indicating Operating Modes

Air-interface	Band(MHz)	Туре	C63.19/tested	Simultaneous Transmissions	ОТТ	Power Reduction
GSM	850	VO	Yes			NA
GSIVI	1900	VO	162	BT, WLAN	NA	INA
CDDC/EDCE	850	DT	NIA			No
GPRS/EDGE	1900	וטן	NA			
	850					
WCDMA	1900	VO	Yes	DT M/LAN	NIA	NA
(UMTS)	1700			BT, WLAN	NA	NA
	HSPA	DT	NA			
LTE	Band 2/4/12	V/D.	NA	BT, WLAN	NA	NA
BT	2450	DT	NA	GSM, WCDMA, LTE	NA	NA
WLAN	2450	DT	NA	GSM, WCDMA, LTE	NA	NA

VO: Voice CMRS/PSTN Service Only

V/D: Voice CMRS/PSTN and Data Service DT: Digital Transport

Note:1.= No Associated T-Coil measurement has been made in accordance with 285076 D02 T-Coil testing for CMRS IP

^{*} HAC Rating was not based on concurrent voice and data modes, Non current mode was found to represent worst case rating for both M and T rating



4 CONDUCTED OUTPUT POWER MEASUREMENT

4.1 Summary

During the process of testing, the EUT was controlled via Agilent Digital Radio Communication tester (E5515C) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured output power should be greater and within 5% than EMI measurement.

4.2 Conducted Power

CCM		Conducted Power (dBm)						
GSM 850MHz	Channel 251(848.8MHz)	Channel 190(836.6MHz)	Channel 128(824.2MHz)					
OSUMINZ	32.71	32.68	32.55					
GSM	Conducted Power(dBm)							
1900MHz	Channel 810(1909.8MHz)	Channel 661(1880MHz)	Channel 512(1850.2MHz)					
I 900IVITIZ	30.24	30.09	30.01					
WCDMA		Conducted Power (dBm)						
850MHz	Channel 4233(846.6MHz)	Channel 4182(836.4MHz)	Channel 4132(826.4MHz)					
OOUWINZ	23.60	23.56	23.54					
WCDMA		Conducted Power (dBm)						
1700MHz	Channel 1513 (1752.6MHz)	Channel 1412 (1732.4MHz)	Channel 1312 (1712.4MHz)					
17 OUNITZ	23.65	23.78	23.70					
WCDMA		Conducted Power (dBm)						
1900MHz	Channel 9538(1907.6MHz)	Channel 9400(1880MHz)	Channel 9262(1852.4MHz)					
TSUUIVITZ	23.69	23.80						
LTE	Conducted Power (dBm)							
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)					
QPSK	23.75	24.01						
LTE		Conducted Power (dBm)						
Band4	Channel 20300(1745MHz)	Channel20175(1732.5MHz)	Channel 20050(1720MHz)					
QPSK	23.87	23.81	23.78					
LTE		Conducted Power (dBm)						
Band12	Channel 23130(711MHz)	Channel 23095(707.5MHz)	Channel23060(704MHz)					
QPSK	23.79	23.63	23.80					
LTE		Conducted Power (dBm)						
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)					
16-QAM	23.15	23.19	23.20					
LTE	Conducted Power (dBm)							
Band4	Channel 20300(1745MHz)	Channel20175(1732.5MHz)	Channel 20050(1720MHz)					
16-QAM	23.09	22.94	23.02					
LTE		Conducted Power (dBm)						
Band12	Channel 23130(711MHz)	Channel 23095(707.5MHz)	Channel23060(704MHz)					
16-QAM	23.05	23.20	23.05					



5 Reference Documents

5.1 Reference Documents for testing

The following document listed in this section is referred for testing.

Reference	Title	Version
ANSI C63.19-2011	American National Standard for Methods of Measurement	2011
	of Compatibility between Wireless Communication Devices	Edition
	and Hearing Aids	
FCC 47 CFR §20.19	Hearing Aid Compatible Mobile Headsets	2015
		Edition
KDB 285076 D01	Equipment Authorization Guidance for Hearing Aid	v04
	Compatibility	



60PERATIONAL CONDITIONS DURING TEST

6.1 HAC MEASUREMENT SET-UP

These measurements are performed using the DASY5 NEO automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists ofhigh precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. A cell controller system contains the power supply, robot controller, teach pendant (Joystick),and remote control, is used to drive the robot motors. The PC consists of the HP Intel Core21.86 GHz computer with Windows XP system and HAC Measurement Software DASY5 NEO, A/D interface card, monitor, mouse, and keyboard. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE)circuit performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

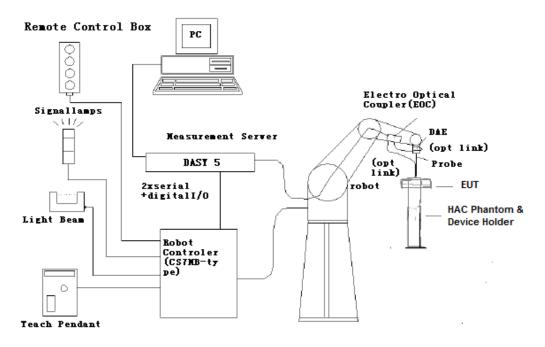


Fig. 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



6.2 Probe Specification

E-Field Probe Description

Construction One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

PEEK enclosure material

Calibration In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%,

k=2)

Frequency 40 MHz to > 6 GHz (can be extended to < 20 MHz)

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity ± 0.2 dB in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

DynamicRange 2 V/m to > 1000 V/m; Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

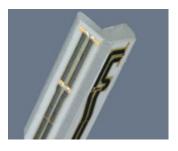
Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm

Application General near-field measurements up to 6 GHz

Field component measurements

Fast automatic scanning in phantoms



[ER3DV6]



6.3Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: $370 \times 370 \times 370 \text{ mm}$).

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field $<\pm 0.5$ dB.



Fig. 2 HAC Phantom & Device Holder

6.4Robotic System Specifications

Specifications

Positioner: Stäubli Unimation Corp. Robot Model: RX160L

Repeatability: ±0.02 mm

No. of Axis: 6

Data Acquisition Electronic (DAE) System

Cell Controller

Processor: Intel Core2 Clock Speed: 1.86GHz

Operating System: Windows XP

Data Converter

Features: Signal Amplifier, multiplexer, A/D converter, and control logic

Software: DASY5 software

Connecting Lines: Optical downlink for data and status info.

Optical uplink for commands and clock



7EUT ARRANGEMENT

7.1 WD RF Emission Measurements Reference and Plane

Figure 4 illustrates the references and reference plane that shall be used in the WD emissions measurement.

- The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids.
- The grid is centered on the audio frequency output transducer of the WD (speaker or T-coil).
- The grid is located by reference to a reference plane. This reference plane is the planar area that contains the highest point in the area of the WD that normally rests against the user's ear
- •The measurement plane is located parallel to the reference plane and 15 mm from it, out from the phone. The grid is located in the measurement plane.

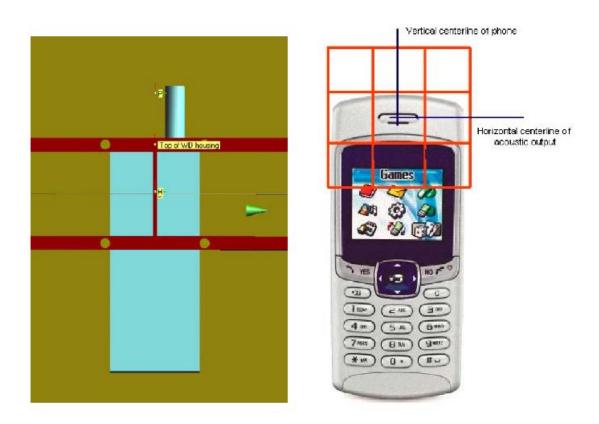


Fig. 3 WD reference and plane for RF emission measurements



8SYSTEM VALIDATION

8.1 Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical output. Position the E-field probes so that:

- •The probes and their cables are parallel to the coaxial feed of the dipole antenna
- •The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions
- The center point of the probe element(s) are 15 mm from the closest surface of the dipole elements.

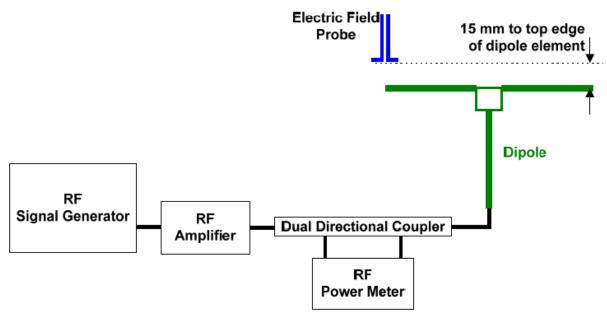


Fig. 4 Dipole Validation Setup

8.2 Validation Result

	E-Field Scan								
Mode Frequency Input Power Measured ¹ Target ² Deviation ³ Lim									
	(MHz)	(mW)	Value(dBV/m)	Value(dBV/m)	(%)	(%)			
CW	835	100	40.48	40.54	-0.69	±25			
CW	1880	100	39.12	39.35	-2.61	±25			

Notes:

- 1. Please refer to the attachment for detailed measurement data and plot.
- 2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.
- 3. Deviation (%) = 100 * (Measured value minus Target value) divided by Target value.
- 4. ANSI C63.19 requires values within \pm 25% are acceptable, of which 12% is deviation and 13% is measurement uncertainty. Values in dependently validated for the dipole actually used in the measurements should be used, when available.



9Evaluation of MIF

9.1 Introduction

The MIF (Modulation Interference Factor) is used to classify E-field emission to determine Hearing Aid Compatibility (HAC). It scales the power-averaged signal to the RF audio interference level and is characteristic to a modulation scheme. The HAC standard preferred "indirect" measurement method is based on average field measurement with separate scaling by the MIF. With an Audio Interference Analyzer (AIA) designed by SPEAG specifically for the MIF measurement, these values have been verified by practical measurements on an RF signal modulated with each of the waveforms. The resulting deviations from the simulated values are within the requirements of the HAC standard.

The AIA (Audio Interference Analyzer) is an USB powered electronic sensor to evaluate signals in the frequency range 698MHz - 6 GHz. It contains RMS detector and audio frequency circuits for sampling of the RF envelope.

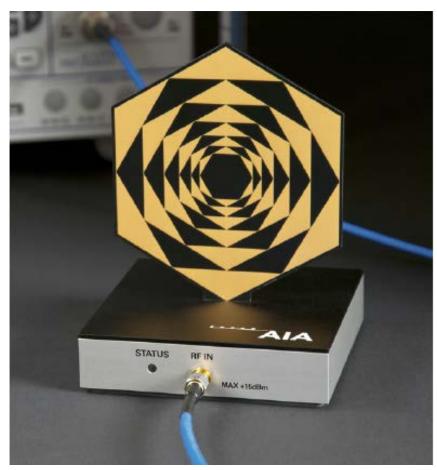


Fig. 5 AIA Front View



9.2MIF measurement with the AIA

The MIF is measured with the AIA as follows:

- 1. Connect the AIA via USB to the DASY5 PC and verify the configuration settings.
- 2. Couple the RF signal to be evaluated to an AIA via cable or antenna.
- 3. Generate a MIF measurement job for the unknown signal and select the measurement port and timing settings.
- 4. Document the results via the post processor in a report.

9.3Test equipment for the MIF measurement

No.	Name	Туре	Serial Number	Manufacturer
01	Signal Generator	E4438C	MY49071430	Agilent
02	AIA	SE UMS 170 CB	1029	SPEAG
03	BTS	E5515C	MY50263375	Agilent

9.4 Test signal validation

The signal generator (E4438C) is used to generate a 1GHz signal with different modulation in the below table based on the ANSI C63.19-2011. The measured MIF with AIA are compared with the target values given in ANSI C63.19-2011 table D.3, D.4 and D5.

Pulse modulation	Target MIF	Measured MIF	Deviation
0.5ms pulse, 1000Hz repetition rate	-0.9 dB	-0.9 dB	0 dB
1ms pulse, 100Hz repetition rate	+3.9 dB	+3.7 dB	0.2 dB
0.1ms pulse, 100Hz repetition rate	+10.1 dB	+10.0 dB	0.1 dB
10ms pulse, 10Hz repetition rate	+1.6 dB	+1.7 dB	0.1 dB
Sine-wave modulation	Target MIF	Measured MIF	Deviation
1 kHz, 80% AM	-1.2 dB	-1.3 dB	0.1 dB
1 kHz, 10% AM	-9.1 dB	-9.0 dB	0.1 dB
1 kHz, 1% AM	-19.1 dB	-18.9 dB	0.2 dB
100 Hz, 10% AM	-16.1 dB	-16.0 dB	0.1 dB
10 kHz, 10% AM	-21.5 dB	-21.6 dB	0.1 dB
Transmission protocol	Target MIF	Measured MIF	Deviation
GSM; full-rate version 2; speech codec/handset low	+3.5 dB	+3.47 dB	0.03 dB
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB	-19.8 dB	0.2 dB
CDMA; speech; SO3; RC3; full frame rate; 8kEVRC	-19.0 dB	-19.1 dB	0.1 dB
CDMA; speech; SO3; RC1; 1/8 th frame rate; 8kEVRC	+3.3 dB	+3.44 dB	0.14 dB



9.5 DUTMIF results

Typical MIF levels in ANSI C63.19-2011					
Transmission protocol	Modulation interference factor				
GSM; full-rate version 2; speech codec/handset low	+3.5 dB				
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB				

	Measured MIF lev	els
Band	Channel	Modulation interference factor
	251	+3.50dB
GSM 850	190	+3.49dB
	128	+3.48dB
	810	+3.45dB
GSM 1900	661	+3.47dB
	512	+3.49dB
	4233	-19.80 dB
WCDMA 850	4182	-19.78 dB
	4132	-19.81 dB
	1513	-19.74 dB
WCDMA 1700	1412	-19.78 dB
	1312	-19.76 dB
	9538	-19.74 dB
WCDMA 1900	9400	-19.75 dB
	9262	-19.76 dB
	19100	-21.20 dB
LTE Band2 QPSK	18900	-22.52 dB
	18700	-21.68 dB
	20300	-22.15 dB
LTE Band4 QPSK	20175	-21.71 dB
	20050	-22.15 dB
	23130	-20.34 dB
LTE Band12 QPSK	23095	-20.81 dB
	23060	-20.52 dB
	19100	-17.92 dB
LTE Band2 16-QAM	18900	-17.41 dB
	18700	-17.12 dB
	20300	-17.28 dB
LTE Band4 16-QAM	20175	-17.82 dB
	20050	-17.45 dB
	23130	-16.96 dB
LTE Band12 16-QAM	23095	-16.13 dB
	23060	-16.12 dB



10 Evaluation for low-power exemption

10.1 Product testing threshold

There are two methods for exempting an RF air interface technology from testing. The first method requires evaluation of the MIF for the worst-case operating mode. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is \leq 17 dBm for any of its operating modes. The second method does not require determination of the MIF. The RF emissions testing exemption shall be applied to an RF air interface technology in a device whose peak antenna input power, averaged over intervals \leq 50 μ s20, is \leq 23 dBm. An RF air interface technology that is exempted from testing by either method shall be rated as M4. The first method is used to be exempt from testing for the RF air interface technology in this report.

10.2 Conducted power

Band	Average power (dBm)	MIF (dB)	Sum (dBm)
GSM 850	32.71	+3.50	36.21
GSM 1900	30.24	+3.45	33.69
WCDMA 850	23.60	-19.80	3.80
WCDMA 1700	23.78	-19.78	4.00
WCDMA 1900	23.80	-19.76	4.04
LTE Band2 QPSK	24.01	-21.68	2.33
LTE Band4 QPSK	23.87	-22.15	1.72
LTE Band12 QPSK	23.80	-20.52	3.28
LTE Band2 16-QAM	23.20	-17.12	6.08
LTE Band4 16-QAM	23.09	-17.28	5.81
LTE Band12 16-QAM	23.20	-16.13	7.07

10.3 Conclusion

According to the above table, the sums of average power and MIF for UMTS and LTE are less than 17dBm. So it is only measured for GSM bands. The UMTS and LTE bands are exempt from testing and rated as M4.



11 RF TEST PROCEDUERES

The evaluation was performed with the following procedure:

- 1) Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
- 2) Position the WD in its intended test position. The gauge block can simplify this positioning.
- 3) Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
- 4) The center sub-grid shall centered on the center of the T-Coil mode axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
- 5) Record the reading.
- 6) Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
- 7) Identify the five contiguous sub-grids around the center sub-grid whose maximum reading is the lowest of all available choices. This eliminates the three sub-grids with the maximum readings. Thus, the six areas to be used to determine the WD's highest emissions are identified.
- 8) Identify the maximum field reading within the non-excluded sub-grids identified in Step 7)
- 9) Evaluate the MIF and add to the maximum steady-state rms field-strength reading to obtain the RF audio interference level..
- 10) Compare this RF audio interference level with the categories and record the resulting WD category rating.



12Measurement Results (E-Field)

Fred	quency	Measured	Down Drift (dD)	Catamami				
MHz	Channel	Value(dBV/m)	Power Drift (dB)	Category				
	GSM 850							
848.8	251	38.40	-0.13	M4 (see Fig B.1)				
836.6	190	38.72	0.07	M4 (see Fig B.2)				
824.2	128	37.67	37.67 -0.05 M4 (s					
		GSM 19	00					
1909.8	810	26.72	0.15	M4 (see Fig B.4)				
1880	661	29.47	-0.02	M4 (see Fig B.5)				
1850.2	512	29.93	0.12	M4 (see Fig B.6)				

13ANSIC 63.19-2011 LIMITS

WD RF audio interference level categories in logarithmic units

Emission categories	< 960 MHz				
	E-field er	missions			
Category M1	50 to 55	dB (V/m)			
Category M2	45 to 50	dB (V/m)			
Category M3	40 to 45 dB (V/m)				
Category M4	< 40 dB (V/m)				
Emission categories	> 96	0 MHz			
	E-field e	missions			
Category M1	40 to 45	dB (V/m)			
Category M2	35 to 40 dB (V/m)				
Category M3	30 to 35 dB (V/m)				
Category M4	< 30	dB (V/m)			



14 MEASUREMENT UNCERTAINTY

No.	Error source	Туре	Uncertainty Value(%)	Prob. Dist.	k	c _i E	Standard Uncertainty (%) $u_i^{'}$ (%)E	Degree of freedom V _{eff} or <i>v</i> _i
	urement System	В		NI.	4		F.4	∞
1	Probe Calibration	В	5.	N	1	1	5.1	ω
2	Axial Isotropy	В	4.7	R	$\sqrt{3}$	1	2.7	∞
3	Sensor Displacement	В	16.5	R	$\sqrt{3}$	1	9.5	∞
4	Boundary Effects	В	2.4	R	$\sqrt{3}$	1	1.4	∞
5	Linearity	В	4.7	R	$\sqrt{3}$	1	2.7	∞
6	Scaling to Peak Envelope Power	В	2.0	R	$\sqrt{3}$	1	1.2	∞
7	System Detection Limit	В	1.0	R	$\sqrt{3}$	1	0.6	∞
8	Readout Electronics	В	0.3	N	1	1	0.3	∞
9	Response Time	В	0.8	R	$\sqrt{3}$	1	0.5	∞
10	Integration Time	В	2.6	R	$\sqrt{3}$	1	1.5	8
11	RF Ambient Conditions	В	3.0	R	$\sqrt{3}$	1	1.7	∞
12	RF Reflections	В	12.0	R	$\sqrt{3}$	1	6.9	∞
13	Probe Positioner	В	1.2	R	$\sqrt{3}$	1	0.7	∞
14	Probe Positioning	А	4.7	R	$\sqrt{3}$	1	2.7	∞
15	Extra. And Interpolation	В	1.0	R	$\sqrt{3}$	1	0.6	∞
Test	Sample Related					•		
16	Device Positioning Vertical	В	4.7	R	$\sqrt{3}$	1	2.7	8
17	Device Positioning Lateral	В	1.0	R	$\sqrt{3}$	1	0.6	∞
18	Device Holder and Phantom	В	2.4	R	$\sqrt{3}$	1	1.4	∞
19	Power Drift	В	5.0	R	$\sqrt{3}$	1	2.9	∞



20	AIA measurement	В	12	R	$\sqrt{3}$	1	6.9	∞
Pha	ntom and Setup related							
21	Phantom Thickness	В	2.4	R	$\sqrt{3}$	1	1.4	∞
Coml	oined standard uncertainty(%)						16.2	
Expanded uncertainty (confidence interval of 95 %)		ι	$u_e = 2u_c$	Z	k=	2	32.4	

15 MAIN TEST INSTRUMENTS

Table 1: List of Main Instruments

No.	Name	Туре	Serial Number	Calibration Date	Valid Period
01	Signal Generator	E4438C	MY49071430	February 01,2016	One Year
02	Power meter	NRVD	102196	March03,2016	One year
03	Power sensor	NRV-Z5	100596		
04	Amplifier	60S1G4	0331848	No Calibration Requested	
05	E-Field Probe	ER3DV6	2272	January19, 2016	One year
06	HAC Dipole	CD835V3	1023	August31, 2016	One year
07	HAC Dipole	CD1880V3	1018	August31, 2016	One year
08	BTS	E5515C	MY50263375	January 30, 2016	One year
09	DAE	SPEAG DAE4	777	August26, 2016	One year
10	AIA	SE UMS 170 CB	1029	No Calibration Re	quested

16 CONCLUSION

The HAC measurement indicates that the EUT complies with the HAC limits of the ANSIC63.19-2011. The total M-rating is **M4.**

END OF REPORT BODY



ANNEX A TEST LAYOUT



Picture A1:HAC RF System Layout



ANNEX B TEST PLOTS

HAC RF E-Field GSM 850 High

Date: 2016-11-3

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:23.0°C

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

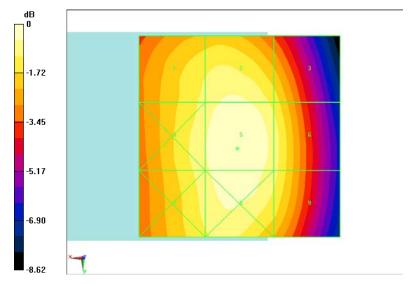
Reference Value = 78.57 V/m; Power Drift = -0.13 dB

Applied MIF = 3.50 dB

RF audio interference level = 38.40 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
37.39 dBV/m	37.89 dBV/m	36.96 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
37.74 dBV/m	38.4 dBV/m	37.5 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
37.59 dBV/m	38.21 dBV/m	37.38 dBV/m



0 dB = 82.47 V/m = 38.33 dBV/m

Fig B.1 HAC RF E-Field GSM 850 High



HAC RF E-Field GSM 850 Middle

Date: 2016-11-3

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:23.0°C

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

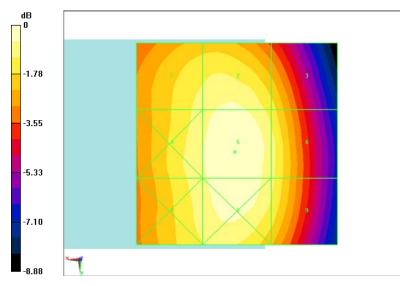
Reference Value = 80.17 V/m; Power Drift = 0.07 dB

Applied MIF = 3.49 dB

RF audio interference level = 38.72 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
37.79 dBV/m	38.24 dBV/m	37.22 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
38.09 dBV/m	38.72 dBV/m	37.78 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
37.99 dBV/m	38.58 dBV/m	37.69 dBV/m



0 dB = 85.94 V/m = 38.68 dBV/m

Fig B.2 HAC RF E-Field GSM 850 Middle



HAC RF E-Field GSM 850 Low

Date: 2016-11-3

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:23.0°C

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

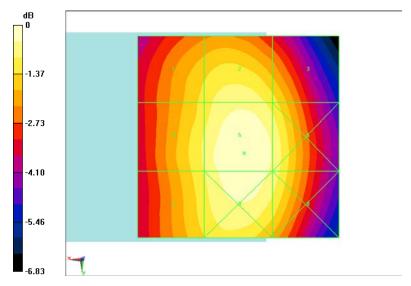
Reference Value = 68.82 V/m; Power Drift = -0.05 dB

Applied MIF = 3.48 dB

RF audio interference level = 37.67 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
36.48 dBV/m	37.09 dBV/m	36.52 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
36.83 dBV/m	37.67 dBV/m	37.15 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
36.74 dBV/m	37.56 dBV/m	37.05 dBV/m



0 dB = 76.28 V/m = 37.65 dBV/m

Fig B.3 HAC RF E-Field GSM 850 Low



HAC RF E-Field GSM 1900 High

Date: 2016-11-3

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:23.0°C

Communication System: DCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 12.63 V/m; Power Drift = 0.15 dB

Applied MIF = 3.45 dB

RF audio interference level = 26.72 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
26.23 dBV/m	23.96 dBV/m	24.02 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
23.71 dBV/m	26.72 dBV/m	26.71 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
27.33 dBV/m	28.22 dBV/m	27.95 dBV/m

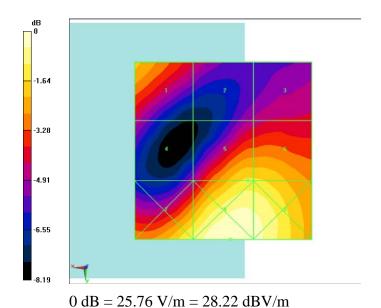


Fig B.4 HAC RF E-Field GSM 1900 High



HAC RF E-Field GSM 1900 Middle

Date: 2016-11-3

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:23.0°C

Communication System: DCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 18.99 V/m; Power Drift = -0.02 dB

Applied MIF = 3.47 dB

RF audio interference level = 29.47 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.6 dBV/m	26.32 dBV/m	26.51 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
25.86 dBV/m	29.47 dBV/m	29.45 dBV/m
Grid 7 M4	Grid 8 M3	Grid 9 M3
28.86 dBV/m	30.18 dBV/m	30.04 dBV/m

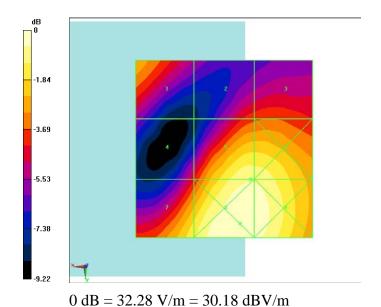


Fig B.5 HAC RF E-Field GSM 1900 Middle



HAC RF E-Field GSM 1900 Low

Date: 2016-11-3

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature:23.0°C

Communication System: DCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 19.63 V/m; Power Drift = 0.12 dB

Applied MIF = 3.49 dB

RF audio interference level = 29.93 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.54 dBV/m	27.08 dBV/m	27.25 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
26.29 dBV/m	29.93 dBV/m	29.92 dBV/m
Grid 7 M4	Grid 8 M3	Grid 9 M3
29.04 dBV/m	30.58 dBV/m	30.47 dBV/m

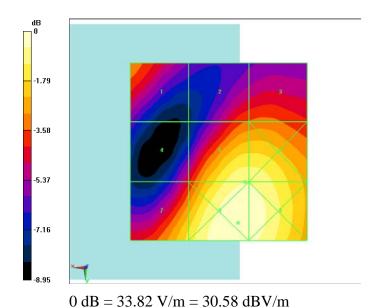


Fig B.6 HAC RF E-Field GSM 1900 Low